

HA17431VPJ/PJ/PAJ/FPJ/FPAJ/PNAJ/UPA, HA17432UPA

Shunt Regulator

REJ03D0892-0100 Rev.1.00 Apr 03, 2007

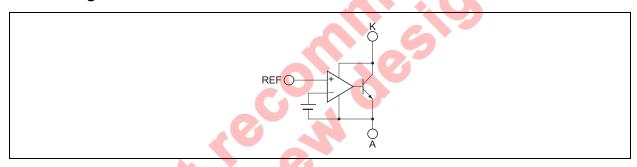
Description

The HA17431 series is temperature-compensated variable shunt regulators. The main application of these products is in voltage regulators that provide a variable output voltage. The on-chip high-precision reference voltage source can provide $\pm 1\%$ accuracy in the V versions, which have a V_{KA} max of 16 volts.

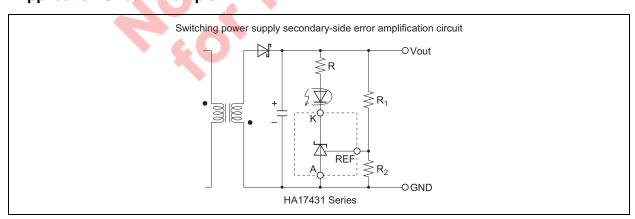
Features

- The V versions provide 2.500 V $\pm 1\%$ at Ta = 25°C
- · The reference voltage has a low temperature coefficient
- The UPAKV miniature packages are optimal for use on high mounting density circuit boards

Block Diagram



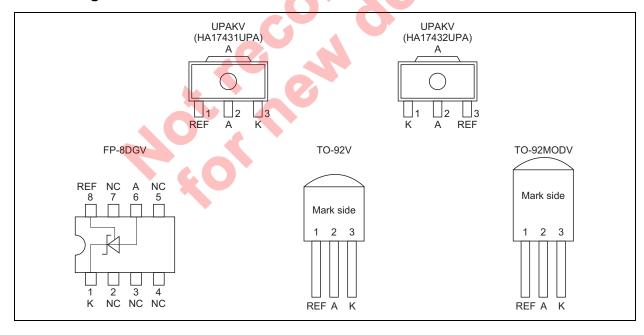
Application Circuit Example



Ordering Information

		Referei	nce voltage (at 2	25°C)		
	Item	Normal Version ±4% 2.395V to 2.495V to 2.595V	A Version ±2.2% 2.440V to 2.495V to 2.550V	V Version ±1% 2.475V to 2.500V to 2.525V	Package Code (Package Name)	Operating Temperature Range
	HA17431FPAJ		0		PRSP0008DE-B (FP-8DGV)	
	HA17431FPJ	0			PRSP0008DE-B (FP-8DGV)	
Car use	HA17431PAJ		0		PRSS0003DC-A (TO-92MODV)	–40 to +85°C
Cai use	HA17431PJ	0			PRSS0003DC-A (TO-92MODV)	-40 to +65 C
	HA17431PNAJ		0		PRSS0003DA-A (TO-92V)	
	HA17431VPJ			0	PRSS0003DA-A (TO-92V)	
Industrial	HA17431UPA		0		PLZZ0004CA-A (UPAKV)	–20 to +85°C
use	HA17432UPA		0		PLZZ0004CA-A (UPAKV)	-20 to +85 C

Pin Arrangement



Absolute Maximum Ratings

 $(Ta = 25^{\circ}C)$

Item	Symbol	HA17431VPJ	HA17431UPA	HA17432UPA	Unit	Notes
Cathode voltage	V _{KA}	16	40	40	V	1
Continuous cathode current	I _K	-50 to +50	-100 to +150	–100 to +150	mA	
Reference input current	Iref	-0.05 to +10	-0.05 to +10	-0.05 to +10	mA	
Power dissipation	P _T	500 * ²	800 * ⁵	800 * ⁵	mW	2, 5
Operating temperature range	Topr	-40 to +85	-20 to +85	–20 to +85	°C	
Storage temperature	Tstg	-55 to +150	-55 to +150	-55 to +150	°C	

Item	Symbol	HA17431PNAJ	HA17431PJ/PAJ	HA17431FPJ/FPAJ	Unit	Notes
Cathode voltage	V_{KA}	40	40	40	V	1
Continuous cathode current	I _K	–100 to +150	-100 to +150	-100 to +150	mA	
Reference input current	Iref	–0.05 to +10	-0.05 to +10	-0.05 to +10	mA	
Power dissipation	P _T	500 * ²	800 *3	500 * ⁴	mW	2, 3, 4
Operating temperature range	Topr	-40 to +85	-40 to +85	-40 to +85	°C	
Storage temperature	Tstg	-55 to +150	-55 to +150	-55 to +125	°C	

Notes: 1. Voltages are referenced to anode.

- 2. Ta \leq 25°C. If Ta > 25°C, derate by 4.0 mW/°C.
- 3. Ta \leq 25°C. If Ta > 25°C, derate by 6.4 mW/°C.
- 4. 50 mm × 50 mm × 1.5mmt glass epoxy board (5% wiring density), Ta ≤ 25°C. If Ta > 25°C, derate by 5 mW/°C.
- 5. 15 mm \times 25 mm \times 0.7mmt alumina ceramic board, Ta \leq 25°C. If Ta > 25°C, derate by 6.4 mW/°C.

Electrical Characteristics

HA17431VPJ

 $(Ta = 25^{\circ}C, I_K = 10 \text{ mA})$

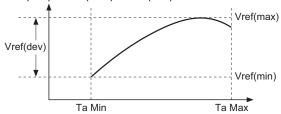
Item	Symbol	Min	Тур	Max	Unit	Test Conditions	Notes
Reference voltage	Vref	2.475	2.500	2.525	V	V _{KA} = Vref	
Reference voltage	Vref(dev)	_	10	_	mV	V _{KA} = Vref,	1
temperature deviation						Ta = -20°C to +85°C	
Reference voltage	∆Vref/∆Ta	_	±30	_	ppm/°C	V _{KA} = Vref,	
temperature coefficient						0°C to 50°C gradient	
Reference voltage regulation	ΔVref/ΔV _{KA}	_	2.0	3.7	mV/V	V _{KA} = Vref to 16 V	
Reference input current	Iref	_	2	6	μΑ	$R_1 = 10 \text{ k}\Omega, R_2 = \infty$	
Reference current	Iref(dev)	_	0.5	_	μΑ	$R_1 = 10 \text{ k}\Omega, R_2 = \infty,$	
temperature						Ta = -20°C to +85°C	
deviation							
Minimum cathode current	lmin	_	0.4	1.0	mA	V _{KA} = Vref	2
Off state cathode current	loff	_	0.001	1.0	μΑ	V _{KA} = 16 V, Vref = 0 V	
Dynamic impedance	Z _{KA}	_	0.2	0.5	Ω	V _{KA} = Vref,	
						$I_K = 1 \text{ mA to } 50 \text{ mA}$	

HA17431PJ/PAJ/FPJ/FPAJ/PNAJ/UPA, HA17432UPA

 $(Ta = 25^{\circ}C, I_K = 10 \text{ mA})$

Item	Symbol	Min	Тур	Max	Unit	Tes	t Conditions	Notes
Reference voltage	Vref	2.440	2.495	2.550	V	V _{KA} = Vref		Α
		2.395	2.495	2.595				Normal
Reference voltage	Vref(dev)	-(11	(30)	mV	V _{KA} = Vref	Ta =	1, 3, 4
temperature deviation							–20°C to +85°C	
			5	(17)			Ta = 0° C to + 70° C	1, 3, 5
Reference voltage	ΔVref/ΔV _{KA}		1.4	3.7	mV/V	V _{KA} = Vref to 10 V		
regulation			1	2.2		V _{KA} = 10 V to 40 V		
Reference input current	Iref	7	3.8	6	μΑ	$R_1 = 10 \text{ k}\Omega$, R ₂ = ∞	
Reference current	Iref(dev)	_	0.5	(2.5)	μА	$R_1 = 10 \text{ k}\Omega$	$R_2 = \infty$,	3
temperature deviation						Ta = 0°C to +70°C		
Minimum cathode current	lmin	_	0.4	1.0	mA	V _{KA} = Vref		2
Off state cathode current	loff) —	0.001	1.0	μА	V _{KA} = 40 V, Vref = 0 V		
Dynamic impedance	ZKA	_	0.2	0.5	Ω	V _{KA} = Vref,		
						$I_K = 1 \text{ mA to}$	100 mA	

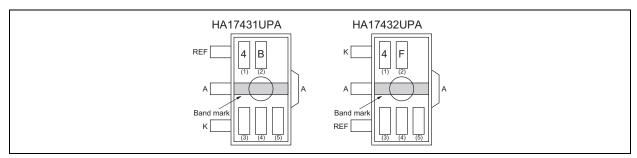
Notes: 1. Vref(dev) = Vref(max) - Vref(min)



- 2. Imin is given by the cathode current at Vref = $Vref_{(IK=10mA)} 15 \text{ mV}$.
- 3. The maximum value is a design value (not measured).
- 4. HA17431PJ/PAJ/FPJ/FPAJ/PNAJ
- 5. HA17431UPA, HA17432UPA

UPAKV Marking Patterns

The marking patterns shown below are used on UPAKV products. Note that the product code and mark pattern are different. The pattern is laser-printed.



Notes: 1. Boxes (1) to (5) in the figures show the position of the letters or numerals, and are not actually marked on the package.

2. The letters (1) and (2) show the product specific mark pattern.

	Product	(1)	(2)
Ī	HA17431UPA	4	В
Ī	HA17432UPA	4	F

3. The letter (3) shows the production year code (the last digit of the year).

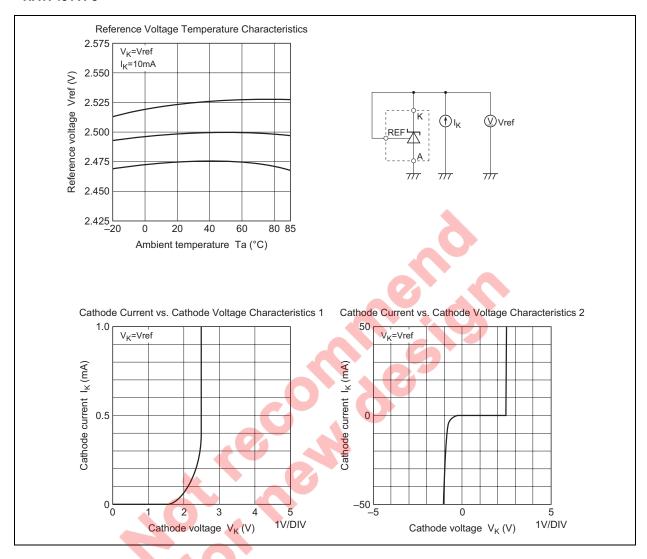
4. The letter (4) shows the production month code (see table below).

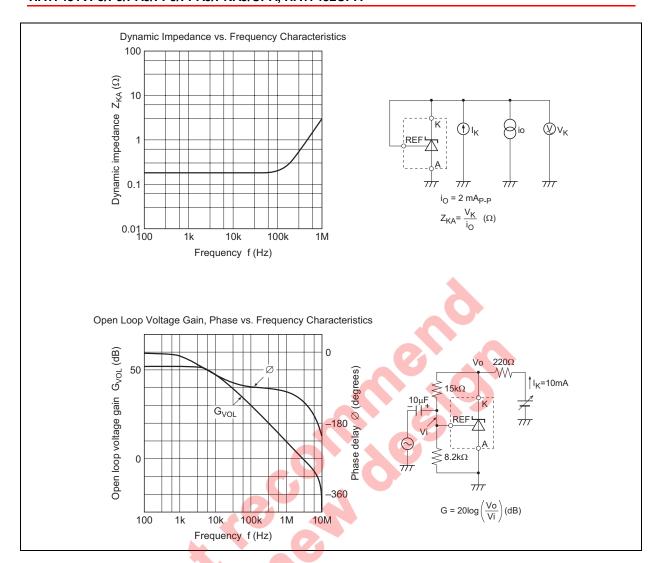
	\ /							,					
Pr	oduction month	Jan.	Feb.	Mar.	Apr.	May.	Jun.	Jul.	Aug.	Sep.	Oct.	Nov.	Dec.
Ma	arked code	Α	В	С	D	E	F	G	H	J	K	L	М
. Th	The letter (5) shows manufacturing code.												
			~										
			1	,									
		81											



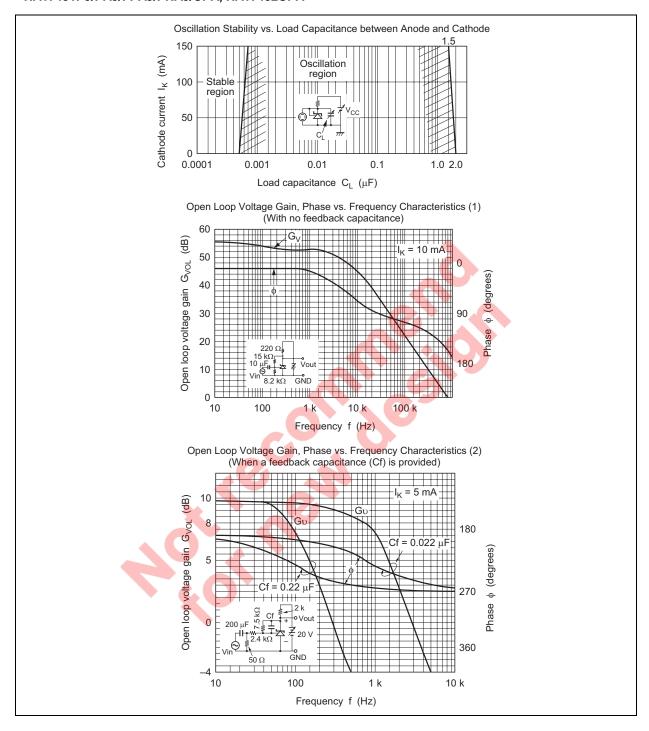
Characteristics Curves

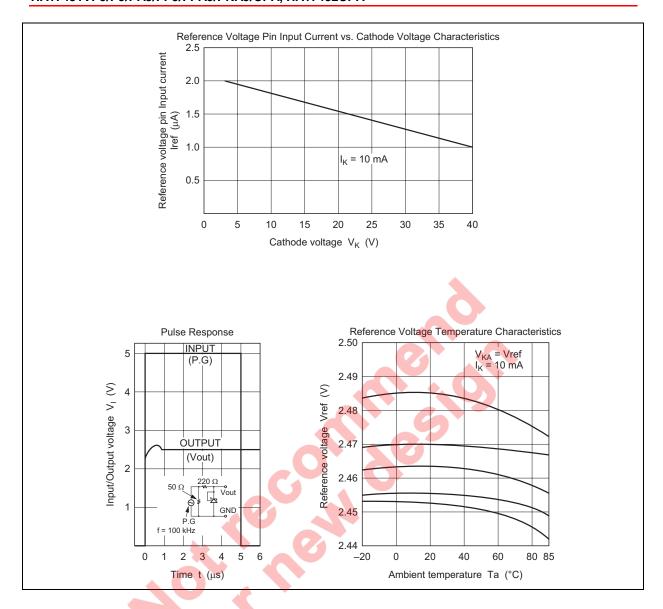
HA17431VPJ

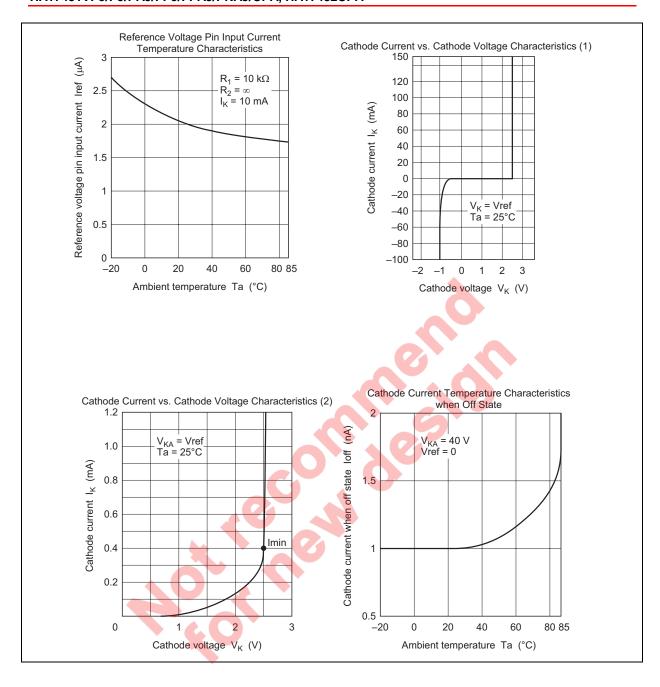




HA17431PJ/PAJ/FPAJ/PNAJ/UPA, HA17432UPA







Application Examples

As shown in the figure on the right, this IC operates as an inverting amplifier, with the REF pin as input pin. The open-loop voltage gain is given by the reciprocal of "reference voltage deviation by cathode voltage change" in the electrical specifications, and is approximately 50 to 60 dB. The REF pin has a high input impedance, with an input current Iref of 3.8 μ A Typ (V version: Iref = 2 μ A Typ). The output impedance of the output pin K (cathode) is defined as dynamic impedance Z_{KA} , and Z_{KA} is low (0.2 Ω) over a wide cathode current range. A (anode) is used at the minimum potential, such as ground.

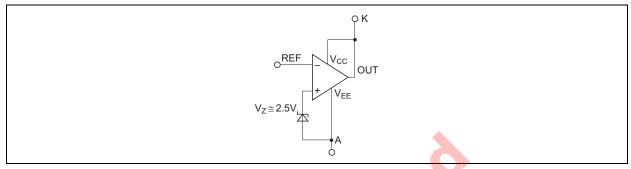


Figure 1 Operation Diagram

Application Hints

No.	Application Example	Description
1	Reference voltage generation circuit Vin O VV Vout REF A GND O GND	This is the simplest reference voltage circuit. The value of the resistance R is set so that cathode current $I_K \ge 1$ mA. Output is fixed at Vout $\cong 2.5$ V. The external capacitor C_L ($C_L \ge 3.3$ μF) is used to prevent oscillation in normal applications.
2	Variable output shunt regulator circuit VinO—VVV R R1 Iref R2 GNDO—OGND	This is circuit 1 above with variable output provided. Here, Vout $\cong 2.5 \text{ V} \times \frac{(R_1+R_2)}{R_2}$ Since the reference input current Iref = 3.8 μ A Typ (V version: Iref = 2 μ A Typ) flows through R_1 , resistance values are chosen to allow the resultant voltage drop to be ignored.

Application Hints (cont.)

No.	Application Example	Description
3	Single power supply inverting comparator circuit	This is an inverting type comparator with an input threshold voltage of approximately 2.5 V. Rin is the REF pin protection resistance, with a value of several $k\Omega$ to several tens of $k\Omega$. R_L is the load resistance, selected so that the cathode current $I_K \ge 1$ mA when Vout is low.
	Rin K Vin O Vout REF A GND O O GND	Condition Vin Vout IC C1 Less then 2.5 V V _{CC} (V _{OH}) OFF C2 2.5 V or more Approx. 2 V (V _{OL}) ON
4	AC amplifier circuit $ \begin{array}{c c} Cf & & & & & \\ \hline & & & & & \\ \hline & & & & \\ \hline & & & &$	This is an AC amplifier with voltage gain $G = -R_1 / (R_2 / / R_3)$. The input is cut by capacitance Cin, so that the REF pin is driven by the AC input signal, centered on 2.5 V_{DC} . R_2 also functions as a resistance that determines the DC cathode potential when there is no input, but if the input level is low and there is no risk of Vout clipping to V_{CC} , this can be omitted. To change the frequency characteristic, Cf should be connected as indicated by the dotted line.
5	Switching power supply error amplification circuit Secondary side GND Note: LED: Light emitting diode in photocoupler R3: Bypass resistor to feed IK(>Imin) when LED current vanishes R4: LED protection resistance	This circuit performs control on the secondary side of a transformer, and is often used with a switching power supply that employs a photocoupler for offlining. The output voltage (between V+ and V-) is given by the following formula:

RENESAS

Application Hints (cont.)

No.	Application Example	Description
6	Constant voltage regulator circuit $V_{CC} \circ R_1 \longrightarrow R_2 \circ V_{OUT} \circ R_3 \circ GND \circ GND$	This is a 3-pin regulator with a discrete configuration, in which the output voltage $Vout = 2.5 \ V \times \frac{(R_2 + R_3)}{R_3}$ R ₁ is a bias resistance for supplying the HA17431 cathode current and the output transistor Q base current.
7	Discharge type constant current circuit VCC R Q 2.5 V Rs GND GND	This circuit supplies a constant current of $I_L\cong\frac{2.5\text{V}}{R_S} [A] \ \ \text{into the load.} \ \ \text{Caution is required}$ since the HA17431 cathode current is also superimposed on $I_L.$ The requirement in this circuit is that the cathode current must be greater than Imin = 1 mA. The I_L setting therefore must be on the order of several mA or more.
8	Induction type constant current circuit Vcc R Q Q GND Q 2.5 V Rs	In this circuit, the load is connected on the collector side of transistor Q in circuit 7 above. In this case, the load floats from GND, but the HA17431 cathode current is not superimposed on I _L , so that I _L can be kept small (1 mA or less is possible). The constant current value is the same as for circuit 7 above: $I_L \cong \frac{2.5 \text{ V}}{R_S} [A]$

Design Guide for AC-DC SMPS (Switching Mode Power Supply)

Use of Shunt Regulator in Transformer Secondary Side Control
 This example is applicable to both forward transformers and flyback transformers. A shunt regulator is used on the secondary side as an error amplifier, and feedback to the primary side is provided via a photocoupler.

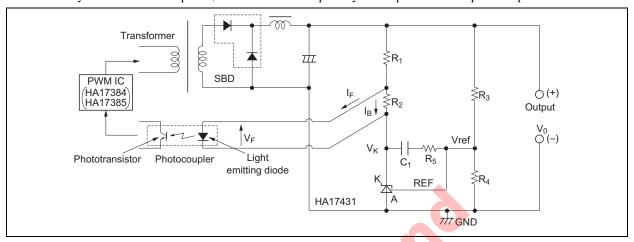


Figure 2 Typical Shunt Regulator/Error Amplifier

- 2. Determination of External Constants for the Shunt Regulator
 - A. DC characteristic determination

In figure 2, R_1 and R_2 are protection resistor for the light emitting diode in the photocoupler, and R_2 is a bypass resistor to feed I_K minimum, and these are determined as shown below. The photocoupler specification should be obtained separately from the manufacturer. Using the parameters in figure 2, the following formulas are obtained:

$$R_1 = \frac{V_0 - V_F - V_K}{I_F + I_B}$$
 , $R_2 = \frac{V_F}{I_B}$

 V_K is the HA17431 operating voltage, and is set at around 3 V, taking into account a margin for fluctuation. R_2 is the current shunt resistance for the light emitting diode, in which a bias current I_B of around 1/5 I_F flows.

Next, the output voltage can be determined by R3 and R4, and the following formula is obtained:

$$V_0 = \frac{R_3 + R_4}{R_4} \times Vref, Vref = 2.5 V Typ$$

The absolute values of R_3 and R_4 are determined by the HA17431 reference input current Iref and the AC characteristics described in the next section. The Iref value is around 3.8 μ A Typ. (V version: 2 μ A Typ)

B. AC characteristic determination

This refers to the determination of the gain frequency characteristic of the shunt regulator as an error amplifier. Taking the configuration in figure 2, the error amplifier characteristic is as shown in figure 3.

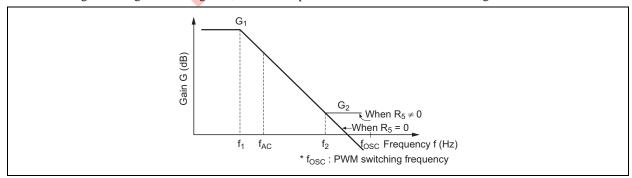


Figure 3 HA17431 Error Amplification Characteristic

In Figure 3, the following formulas are obtained:

Gain

 $G_1 = G_0 \approx 50$ dB to 60 dB (determined by shunt regulator)

$$G_2 = \frac{R_5}{R_3}$$

Corner frequencies

$$f_1 = 1/(2\pi C_1 G_0 R_3)$$

$$f_2 = 1/(2\pi C_1 R_5)$$

 G_0 is the shunt regulator open-loop gain; this is given by the reciprocal of the reference voltage fluctuation $\Delta V ref/\Delta V_{KA}$, and is approximately 50 dB.

3. Practical Example

Consider the example of a photocoupler, with an internal light emitting diode $V_F = 1.05$ V and $I_F = 2.5$ mA, power supply output voltage $V_2 = 5$ V, and bias resistance R_2 current of approximately 1/5 I_F at 0.5 mA. If the shunt regulator $V_K = 3$ V, the following values are found.

$$R_1 = \frac{5V - 1.05V - 3V}{2.5\text{mA} + 0.5\text{mA}} = 316(\Omega) \text{ (330}\Omega \text{ from E24 series)}$$

$$R_2 = \frac{1.05V}{0.5mA} = 2.1(k\Omega) (2.2k\Omega \text{ from E24 series})$$

Next, assume that $R_3 = R_4 = 10 \text{ k}\Omega$. This gives a 5 V output. If $R_5 = 3.3 \text{ k}\Omega$ and $C_1 = 0.022 \mu\text{F}$, the following values are found.

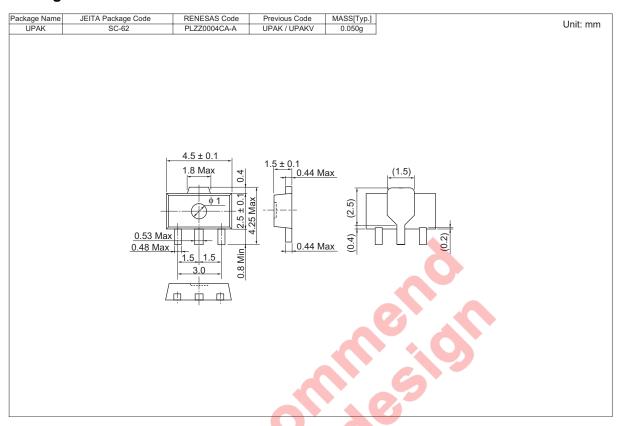
$$G_2 = 3.3 \text{ k}\Omega / 10 \text{ k}\Omega = 0.33 \text{ times (-10 dB)}$$

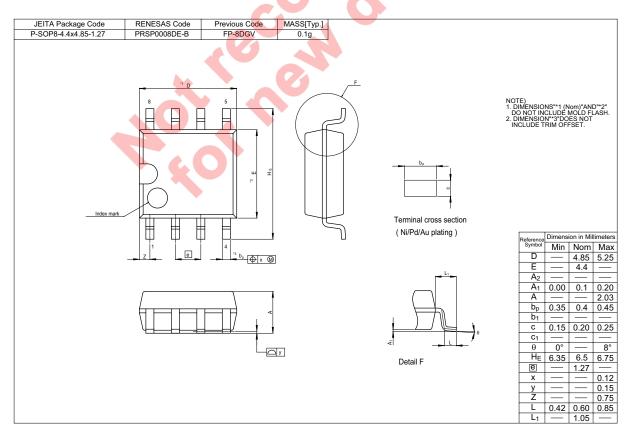
$$f_1 = 1 / (2 \times \pi \times 0.022 \ \mu\text{F} \times 316 \times 10 \ \text{k}\Omega) = 2.3 \ \text{(Hz)}$$

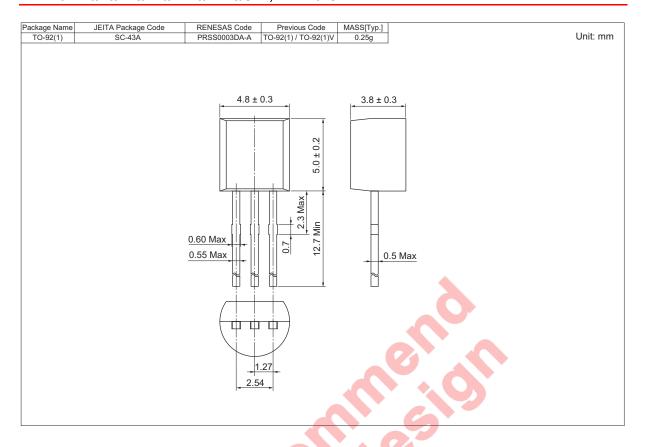
$$f_2 = 1 / (2 \times \pi \times 0.022 \,\mu\text{F} \times 3.3 \,\text{k}\Omega) = 2.2 \,(\text{kHz})$$

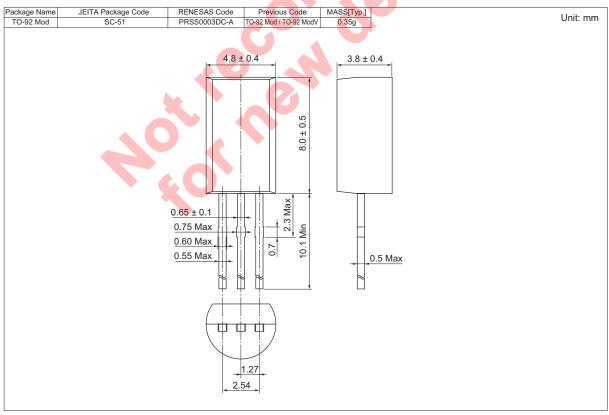


Package Dimensions









Renesas Technology Corp. Sales Strategic Planning Div. Nippon Bldg., 2-6-2, Ohte-machi, Chiyoda-ku, Tokyo 100-0004, Japan

- Renesas Technology Corp. Sales Strategic Planning Div. Nippon Bidg., 2-6-2, Ohte-machi, Chiyoda-ku, Tokyo 100-0004, Japan

 Notes:

 1. Whis document is provided for reference purposes only so that Renesas customers may select the appropriate Renesas groducts for their use. Renesas neither makes in the provided for reference purposes only so that Renesas of the information in this document nor grants any license to any intellectual property infelts or any other rights of Renesas or any third party with report to the information in this document nor grants any license to any intellectual property grants are provided to the products of the response of minimal property or other rights arising out of the use of any information in this document, including, but not limited to, product data, diagrams, algorithms, and application circuit examples.

 3. You should not use the products or the technology described in this document for the purpose of minimal products or technology described in this document or for the purpose of any other military use. When exporting the products or technology described herein, you should follow the applicable export control laws destruction or for the purpose of any other military use. When exporting the products or technology described herein, you should follow the applicable export control laws destruction or for the purpose of any other military superior to the purpose of minimal products and the product of the date this document is issued. Such information, however, is subject to change without any prior notice. Before purchasign or using any Renesas products itself in this document, please confirm the latest product information with a Renesas sales office. Also, please pay regular and careful attention to additional and different information to develope the information in light of the total system before deciding about the applicable of Products of the products of any particular application and specifically disclaims any liability arising out of the application and use of the informatio



Refer to "http://www.renesas.com/en/network" for the latest and detailed information.

RENESAS SALES OFFICES

Renesas Technology America, Inc. 450 Holger Way, San Jose, CA 95134-1368, U.S.A Tel: <1> (408) 382-7500, Fax: <1> (408) 382-7501

Renesas Technology Europe Limited
Dukes Meadow, Millboard Road, Bourne End, Buckinghamshire, SL8 5FH, U.K.
Tel: <44> (1628) 585-100, Fax: <44> (1628) 585-900

Renesas Technology (Shanghai) Co., Ltd.
Unit 204, 205, AZIACenter, No.1233 Lujiazui Ring Rd, Pudong District, Shanghai, China 200120 Tel: <86> (21) 5877-1818, Fax: <86> (21) 6887-7898

Renesas Technology Hong Kong Ltd.
7th Floor, North Tower, World Finance Centre, Harbour City, 1 Canton Road, Tsimshatsui, Kowloon, Hong Kong Tel: <852> 2265-6688, Fax: <852> 2730-6071

Renesas Technology Taiwan Co., Ltd. 10th Floor, No.99, Fushing North Road, Taipei, Taiwan Tel: <886> (2) 2715-2888, Fax: <886> (2) 2713-2999

Renesas Technology Singapore Pte. Ltd. 1 Harbour Front Avenue, #06-10, Keppel Bay Tower, Singapore 098632 Tel: <65> 6213-0200, Fax: <65> 6278-8001

Renesas Technology Korea Co., Ltd. Kukje Center Bldg. 18th Fl., 191, 2-ka, Hangang-ro, Yongsan-ku, Seoul 140-702, Korea Tel: <82> (2) 796-3115, Fax: <82> (2) 796-2145

Renesas Technology Malaysia Sdn. Bhd
Unit 906, Block B, Menara Amcorp, Amcorp Trade Centre, No.18, Jalan Persiaran Barat, 46050 Petaling Jaya, Selangor Darul Ehsan, Malaysia Tel: <603> 7955-9390, Fax: <603> 7955-9510

http://www.renesas.com